# mail

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# 1. General description

Planar passivated Silicon Controlled Rectifier in a SOT1259 (3-lead TO-3P) plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

## 2. Features and benefits

- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- High voltage capacity
- · Very high current surge capability

## 3. Applications

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control
- Uninterruptible Power Supply (UPS)
- Solid State Relay (SSR)
- Traction battery charging

# 4. Quick reference data

Table 1. Quic	k reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		-	-	1200	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	-	1200	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	650	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	-	715	A
Tj	junction temperature		-	-	150	°C
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{mb} \leq 131 \text{ °C}$	-	-	50	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	79	A

# BT155K-1200T

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static charact	eristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C}; \text{ Fig. 7}; \text{Fig. 8}$	-	-	50	mA
Dynamic char	acteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 800 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform	1500	-	-	V/µs

# 5. Pinning information

#### Table 2. Pinning information Pin Symbol Description **Simplified outline Graphic symbol** 1 Κ cathod А₽К $\bigcirc \bigcirc \land$ Ġ 2 А anode sym037 3 G gate 0 mb mb mounting base; connected to anode 2 3 TO3P (SOT1259)

# 6. Ordering information

Fable 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BT155K-1200T	ТОЗР	Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO3P	SOT1259				

### 7. Marking

Table 4. Marking codes						
	Type number	Marking code				
	BT155K-1200T	BT155K-1200T				

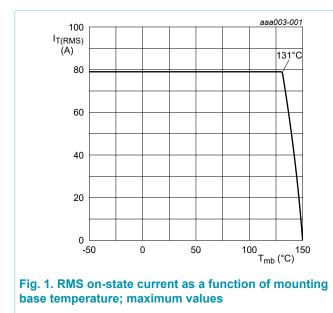
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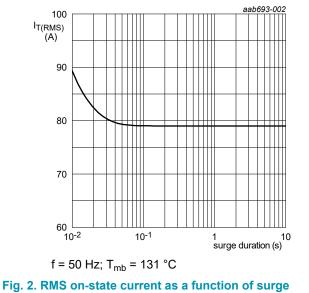
### 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	1200	V
V <sub>RRM</sub>	repetitive peak reverse voltage		-	1200	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C	-	50	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 131 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	79	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5	-	650	A
		half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 8.3 ms	-	715	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	2113	A²s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 200 mA	-	150	A/µs
I <sub>GM</sub>	peak gate current		-	8	А
V <sub>RGM</sub>	peak reverse gate voltage		-	5	V
P <sub>GM</sub>	peak gate power		-	20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

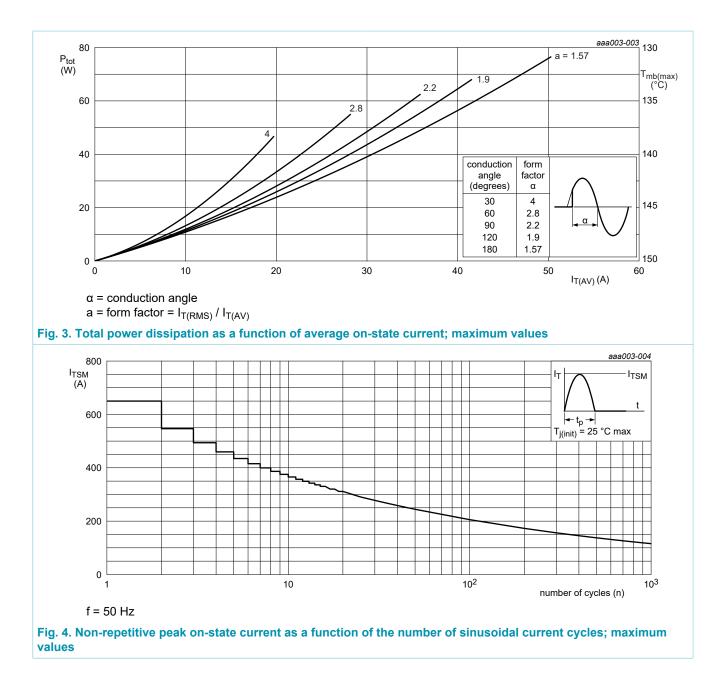




duration; maximum values

# BT155K-1200T

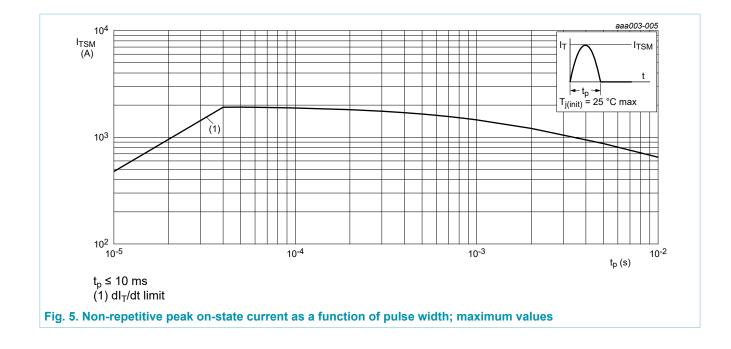
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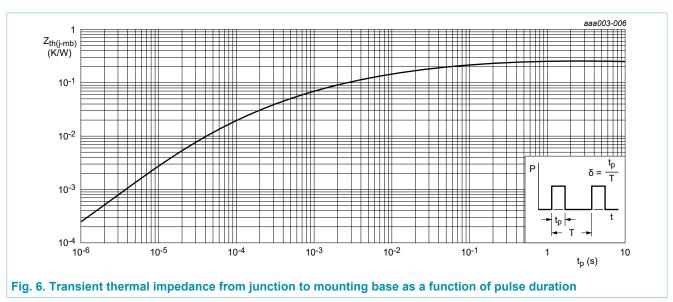
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### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	full cycle; <u>Fig. 6</u>	-	-	0.25	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W



#### BT155K-1200T

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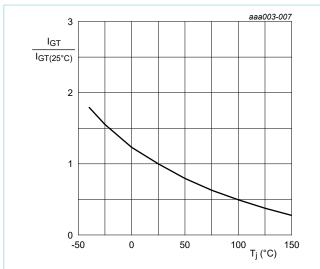
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## **10. Characteristics**

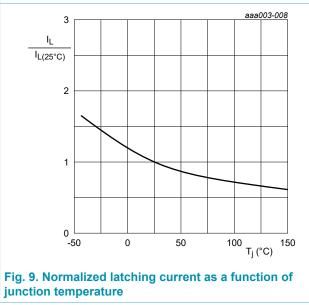
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7;</u> <u>Fig. 8</u>	-	-	50	mA
IL	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	300	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	200	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 50 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.3	V
		I <sub>T</sub> = 90 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.5	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 12	-	0.7	1	V
		V <sub>D</sub> = 800 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C; Fig. 12	0.25	0.4	-	V
ID	off-state current	V <sub>D</sub> = 1200 V; T <sub>j</sub> = 125 °C	-	-	3	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V; T <sub>j</sub> = 125 °C	-	-	3	mA
Dynamic ch	naracteristics	·				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 800 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 100 Ω; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform	1500	-	-	V/µs
		$V_{DM}$ = 800 V; T <sub>j</sub> = 150 °C; R <sub>GK</sub> = 100 Ω; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform	1000	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A}; \text{ V}_{\text{D}} = 800 \text{ V}; \text{ I}_{\text{G}} = 0.1 \text{ A}; \text{ dI}_{\text{G}} / \\ \text{dt} = 5 \text{ A}/\mu\text{s}; \text{ T}_{\text{j}} = 25 ^{\circ}\text{C} $	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	150	-	μs

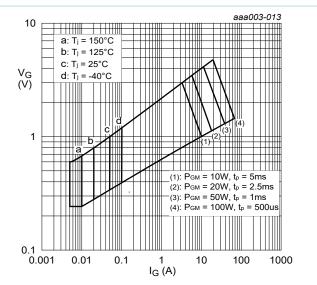
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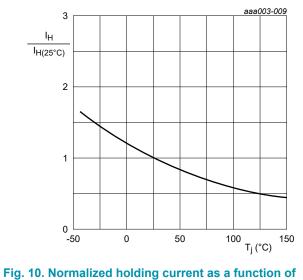


# Fig. 7. Normalized gate trigger current as a function of junction temperature



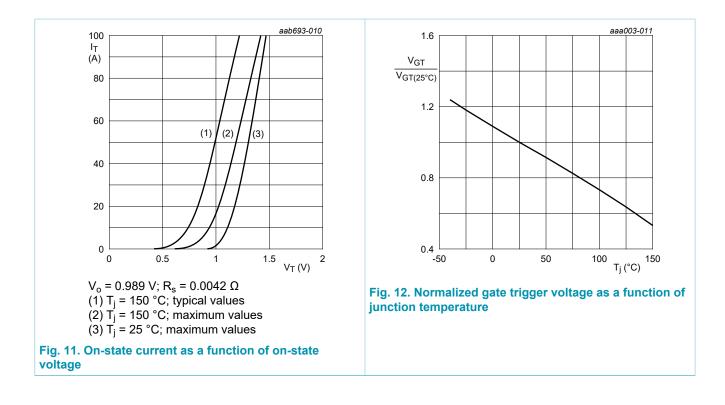




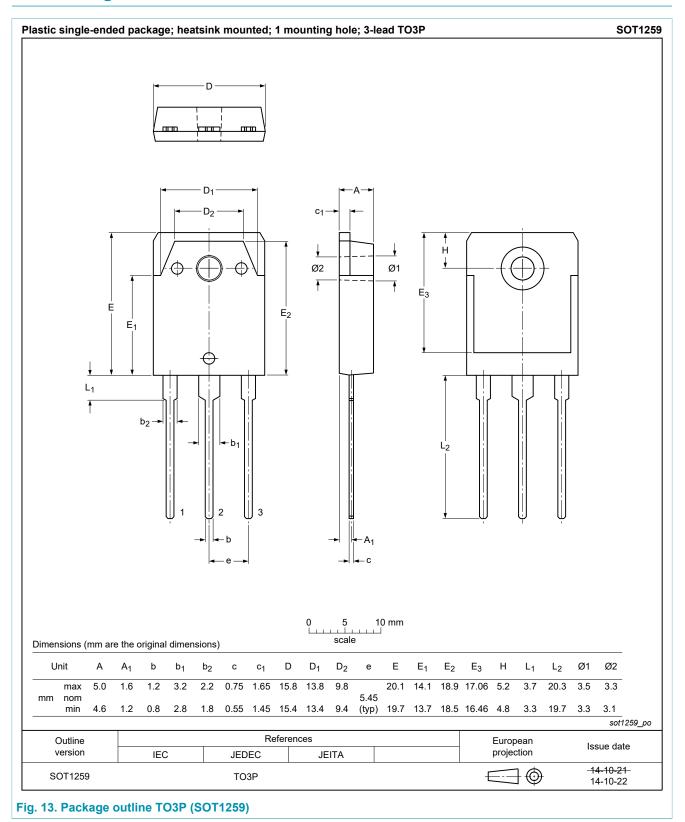


junction temperature

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### **11. Package outline**



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# 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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